



PV module - SS8-72HD-585N

Manufacturer	UNIMACTS	Commercial data	
Model	SS8-72HD-585N	Availability :	Prod. Since 2023
		Data source :	TÜV SÜD
Pnom STC power (manufacturer)	585 Wp	Technology	Si-mono
Module size (W x L)	1.134 x 2.278 m ²	Rough module area (Amodule)	2.58 m ²
Number of cells	2 x 72	Sensitive area (cells) (Acells)	2.38 m ²

Specifications for the model (manufacturer or measurement data)

Reference temperature (TRef)	25 °C	Reference irradiance (GRef)	1000 W/m ²
Open circuit voltage (Voc)	51.7 V	Short-circuit current (Isc)	14.42 A
Max. power point voltage (Vmpp)	42.8 V	Max. power point current (Impp)	13.68 A
=> maximum power (Pmpp)	585.1 W	Isc temperature coefficient (mulsc)	6.5 mA/°C

One-diode model parameters

Shunt resistance (Rshunt)	300 Ω	Diode saturation current (IoRef)	0.019 nA
Serie resistance (Rserie)	0.21 Ω	Voc temp. coefficient (MuVoc)	-124 mV/°C
Specified Pmax temper. coeff. (muPMaxR)	-0.29 %/°C	Diode quality factor (Gamma)	1.02
		Diode factor temper. coeff. (muGamma)	0.000 1/°C

Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch

Reverse characteristics (dark) (BRev)	3.20 mA/V ²	(quadratic factor (per cell))	
Number of by-pass diodes per module	3	Direct voltage of by-pass diodes	-0.7 V

Model results for standard conditions (STC: T=25 °C, G=1000 W/m², AM=1.5)

Max. power point voltage (Vmpp)	42.8 V	Max. power point current (Impp)	13.71 A
Maximum power (Pmpp)	585.1 Wp	Power temper. coefficient (muPmpp)	-0.29 %/°C
Efficiency(/ Module area) (Eff_mod)	22.6 %	Fill factor (FF)	0.785
Efficiency(/ Cells area) (Eff_cells)	24.5 %		

